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Fully Differential Chopper-Stabilized Multipath Current-Feedback Instrumentation Amplifier with R-2R DAC Offset Adjustment for Resistive Bridge Sensors

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Abstract: A fully differential multipath current-feedback instrumentation amplifier (CFIA) for a resistive bridge sensor readout integrated circuit (IC) is proposed. To reduce the CFIA's own offset and 1/f noise, a chopper stabilization technique is implemented. To attenuate the output ripple caused by chopper up-modulation, a ripple reduction loop (RRL) is employed. A multipath architecture is implemented to compensate for the notch in the chopping frequency band of the transfer function. To prevent performance degradation resulting from external offset, a 12-bit R-2R digital-to-analog converter (DAC) is employed. The proposed CFIA has an adjustable gain of 16–44 dB with 5-bit programmable resistors. The proposed resistive sensor readout IC is implemented in a 0.18 μ m complementary metal-oxide-semiconductor (CMOS) process. The CFIA draws 169 μ A currents from a 3.3 V supply. The simulated input-referred noise and noise efficiency factor (NEF) are 28.3 nV/ \sqrt{Hz} and 14.2, respectively. The simulated common-mode rejection ratio (CMRR) is 162 dB, and the power supply rejection ratio (PSRR) is 112 dB.

Keywords: multipath current-feedback instrumentation amplifier (CFIA); resistive bridge sensor readout integrated circuit (IC); chopper stabilization technique; ripple reduction loop (RRL)

1. Introduction

Recently, the Internet of Things (IoT) has played a significant role in many aspects of modern life, such as medical care, automobiles, homes, and amenities [1]. IoT sensors that perceive and collect information and circuits that readout these sensors with high precision are also becoming more important [2]. Resistive micro-electro-mechanical systems (MEMS) sensors that use a piezoresistive effect have various ways, such as strain gauges and pressure, acceleration, and force sensors [3–7]. The need for smaller, less expensive high-performance sensors has developed in a way that makes sensors and sensing elements smaller. To readout these sensors precisely, readout circuits should have low-noise, high input impedance, low power, and high common-mode rejection ratio (CMRR) characteristics. Conventionally, the well-known 3-opamp instrumentation amplifier (IA) scheme features a high input impedance. Its disadvantage is that the degree of matching resistance greatly influences the CMRR, making it difficult to achieve a high CMRR. A current-feedback instrumentation amplifier (CFIA) consists of an input transconductance stage and output Miller integrator stage.



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The CFIA scheme features high input impedance, high CMRR, high open-loop gain, and low power consumption, because the input common-mode (CM) voltage is isolated by the input transconductance stage [8]. Although the CFIA has advantages in terms of its simple structure, the input offset and noise can cause performance degradation. To implement the low-noise characteristics of the instrumentation amplifier (IA), auto-zeroing, correlated double sampling (CDS), and the chopper stabilization technique are the most widely used schemes [9–12]. Unlike thermal noise with a wide

frequency band, flicker noise and DC offset overlap with the sensor output signal. For the desired output voltage of the IA, reduction of flicker noise and DC offset are essential. The auto-zeroing and CDS schemes sample the offsets in the input capacitor of the IA, which attenuates flicker noise and DC offset through comparison and amplification. However, the high-frequency thermal noise folds and appears in integrated form in the baseband because of aliasing. The chopper stabilization technique reduces baseband noise through up-modulating the flicker noise and DC offset in the baseband; thus, a thermal-noise-limited level can be achieved. However, up-modulated DC offset and flicker noise can cause a ripple in the output. To solve this problem, a ripple reduction loop (RRL) is used to demodulate the ripple and provide negative feedback to the input through the integrator [13]. The RRL attenuates the output ripple caused by chopping, but there are disadvantages to generating notches of the transfer function in the chopping frequency band.

In this study, a low-noise bridge resistive sensor readout circuit with dual offset reduction is implemented. (1) The offset inside the amplifier is reduced by the multipath offset stabilization topology. (2) The offset outside the amplifier is adjusted by the R-2R digital-to-analog converter (DAC) in the current-feedback path. To attenuate the flicker noise and DC offset in the baseband, the chopper stabilization technique is employed. The RRL is adopted to attenuate the output ripple. A multipath topology is employed to compensate for the notches of the transfer function in the chopping frequency band. This CFIA achieves a high CMRR, high input impedance, and low power consumption.

2. Circuit Implementation

Figure 1 shows the proposed resistive sensor readout analog-front-end (AFE) IC architecture. The architecture consists of a multipath CFIA, low-pass filter (LPF), buffer, 12-bit successive approximation register analog-to-digital converter (SAR ADC), R-2R DAC, and feedback resistor. To drive a variety of resistive sensors, the feedback resistor R₂ is designed by implementing a 5-bit programmable resistor. Depending on the external 5-bit digital input, the proposed resistive sensor readout AFE has an adjustable gain of 16–44 dB. Figure 2 shows the operation of the R-2R DAC calibration. The R-2R DAC is designed to compensate for the external offset generated by sensor element mismatches. The R-2R DAC has the ability to adjust the amplified external offset voltage between 3.3 V and -3.3V, with 1.61 mV intervals through the 12-bit digital input. The output voltage of the proposed CFIA without the external offset and R-2R DAC is expressed as (1).

$$OUTP - OUTN = \left(1 + 2 \times \frac{R_1}{R_2}\right) \times (INP - INN)$$
(1)

Each unit of the R-2R DAC, consisting of R_D and $2R_D$ resistors, has an output resistance of R_D . The output resistance between the DACP and DACN node can be interpreted as $2R_D$. Therefore, the output voltage of the proposed CFIA with R-2R DAC is expressed as (2).

$$OUTP - OUTN = \left(1 + 2 \times \frac{R_1}{R_2}\right) \times (INP - INN) + \frac{R_1}{R_D} \times ((INP - INN) - (DACP - DACN))$$
(2)

Through the second term of (2), the amplified external offset can be calibrated. In this design, R_1 can influence offset calibration. Therefore, R_{2} , which is independent from offset calibration, is configured as a programmable resistor.



Figure 1. Proposed architecture of resistive sensor readout analog-front-end integrated circuit (IC).



Figure 2. Operation of R-2R digital-to-analog converter (DAC) calibration.

Figure 3 shows the block diagram of the proposed CFIA. The proposed fully differential CFIA circuit consists of two main signal paths: a low-frequency and a high-frequency path. The low-frequency path employs the chopper stabilization technique to reduce flicker noise and DC offset in the baseband. To reduce the ripple caused by chopping, the RRL is implemented. To compensate for the notch in the transfer function of the chopping frequency band, the high-frequency path is used.



Figure 3. Block diagram of the proposed current-feedback instrumentation amplifier (CFIA).

2.1. Low-Frequency Path

The R-2R DAC reduces the offset caused by sensor element mismatches but does not reduce the IA's own internal offset. The chopper implements an internal offset reduction. The chopper is operated by two nonoverlapping clocks. As shown in Figure 3, the sensor output signal is modulated into the high-frequency band through a modulation chopper (CH1), and the modulated signal is demodulated back into the baseband through the demodulation chopper (CH3). Simultaneously, a modulation chopper (CH3) modulates flicker noise and DC offset into the high-frequency band. Consequentially, the up-modulated flicker noise and DC offset are reduced through a Miller integrator (Gm₄) and combined with high-frequency path signals. At the output of the Miller integrator (Gm₄), the up-modulated flicker noise and DC offset generate a ripple. The ripple is negative feedback to the input of the chopper (CH3) through an AC coupling capacitor (C_s) and the current buffer.

The overall input impedance of the CFIA is determined by the switched capacitor resistor, and is generated by the chopping frequency and input parasitic capacitor (C_{p1} , C_{p2} , and C_{p3}). Consequently, the input impedance is inversely proportional to the chopping frequency and input parasitic capacitor. If the chopping frequency is reduced to increase the impedance, the output ripple increases. If the parasitic capacitor is reduced to increase the impedance, flicker noise tends to prevail. Achieving high-performance CFIA requires delicate consideration of trade-offs between noise and input impedance.

2.2. High-Frequency Path

Figure 4 shows a schematic of the high-frequency path. The high-frequency path consists of a three-input transconductance stage and the Miller integrator. The input, feedback, and low-frequency path output signals are converted to currents through Gm₁₁, Gm₁₂, and Gm₅, respectively, and entered into the Miller integrator. At the Gm₃ stage, to achieve a fine-frequency response in the high-frequency path, nested Miller compensation is implemented [14]. To compensate for the drawbacks of the dead-band in the crossover area, a Monticelli class AB output stage is implemented (M17, M18, M19, and M20). It has the advantages of linear output characteristics and distortion reduction. Figure 5 shows a schematic of the high-frequency path common-mode feedback (CMFB) circuit. The gate voltage of transistors M13 and M14 is determined by the active CMFB circuit, which has the advantage

of increasing bandwidth. To stabilize the output voltage, the CMFB circuit is also implemented at the output stage.



Figure 4. Schematic of the high-frequency path.



Figure 5. Schematic of the high-frequency path common-mode feedback (CMFB) circuit.

3. Simulation Results

Figure 6 shows the transient response of a CFIA with a 20mV amplitude input sine wave of 1 kHz. The gain of the CFIA was set to have 11 V/V through a 5-bit programmable resistor. The graph shows the input/output in the form of a differential signal. The output signal is simulated to have a peak value of 220.07 mV at 0.25 ms. Figure 7 shows the simulated transfer function in differential mode, VDD, GND, and common-mode. The simulated CMRR achieves 162 dB. The power supply rejection ratio (PSRR+ and PSRR-) are simulated at 112 and 110 dB, respectively. Figure 8 shows the frequency response of the CFIA. The open-loop gain is simulated at 132.5 dB at 1 mHz. The simulated unit gain bandwidth (UGBW) is 59.2 kHz, and the phase margin is 75.1° at UGBW. Figure 9 shows the simulated input-referred noise. The simulated input-referred noise is 30 nV/ \sqrt{Hz} at 1 Hz and 28.3 nV/ \sqrt{Hz} at 1 kHz.



Figure 6. Transient response of CFIA with 20mV amplitude input sine wave.







Figure 8. (a) Gain of the CFIA and (b) phase of the CFIA.



Figure 9. Simulated input-referred noise of CFIA.

Figure 10 shows the simulated CFIA output DC operating point under R-2R DAC digital input variation. It shows that the offset of the CFIA output can be linearly calibrated within a ± 3.3 V range. The performance summary and comparison with other papers are shown in Table 1. The efficiency of the instrumentation amplifier can be evaluated using a noise efficiency factor (NEF), as shown in (3), where $V_{rms,ni}$ is the input-referred noise RMS value, I_{tot} is the total current consumption, U_T is thermal voltage, and BW is bandwidth of the amplifier.



Figure 10. Simulated CFIA output DC operating point under R-2R DAC digital input variation.

	This Work	[9]	[15]	[16]	[17]
Process (µm)	0.18	0.5	0.7	0.7	0.32
Supply (V)	3.3	3–5.5	5	5.5	3.3
Current (µA)	169	1700	290	325	170
DC gain (dB)	132.5	1000	-	-	201.2
CMRR (dB)	162	142	127	130	>120
PSRR+ (dB)	112	138	130	114	115
PSRR- (dB)	110	-	-	-	-
BW (kHz)	59.2	800	800	640	40
Input-referred noise (nV/√Hz)	28.3	27	17	42	18
NEF	14.2	43	11.2	29.2	10.6

Table 1. Performance summary of proposed current-feedback instrumentation amplifier (CFIA) and
comparison with other instrumentation amplifiers (IAs).

4. Discussion and Conclusions

A fully differential multipath CFIA for a bridge resistive sensor readout IC is presented. The proposed CFIA has the ability to reduce external and internal offsets, thereby achieving low-noise characteristics. To attenuate the internal offset, the chopper stabilization technique is implemented. To reduce the output ripple caused by chopper up-modulation, an RRL is used. A multipath architecture is employed to compensate for the notch in the chopping frequency band of the transfer function. To calibrate external offset, a 12-bit R-2R DAC is adopted. The proposed resistive sensor readout IC is implemented using 0.18 μ m CMOS technology. The current consumption of CFIA is 169 μ A with a 3.3 V supply. The simulated input-referred noise and NEF are 28.3 nV/ \sqrt{Hz} and 14.2, respectively. The CFIA achieves 112 dB PSRR+ and 162 dB CMRR. The proposed CFIA, which achieves low-noise characteristics, is expected to be employed in various resistive IoT sensor applications with high precision.

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